

Diego Calvo Ruiz

List of Publications by Year in descending order

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citing authors

#	ARTICLE	IF	CITATIONS
1	Pt Gate Sink-In Process Details Impact on InP HEMT DC and RF Performance. IEEE Transactions on Semiconductor Manufacturing, 2017, 30, 462-467.	1.7	13
2	InAs Channel Inset Effects on the DC, RF, and Noise Properties of InP pHEMTs. IEEE Transactions on Electron Devices, 2019, 66, 4685-4691.	3.0	10
3	Impact Ionization Control in 50 nm Low-Noise High-Speed InP HEMTs with InAs Channel Insets. , 2019, , .		8
4	Effects of Electrochemical Etching on InP HEMT Fabrication. IEEE Transactions on Semiconductor Manufacturing, 2019, 32, 496-501.	1.7	6
5	Low-Noise Microwave Performance of 30 nm GaInAs MOS-HEMTs: Comparison to Low-Noise HEMTs. IEEE Electron Device Letters, 2020, 41, 1320-1323.	3.9	6
6	High-Speed Steep-Slope GaInAs Impact Ionization MOSFETs (I-MOS) With $SS = 1.25 \text{ mV/dec}$ Part II: Dynamic Switching and RF Performance. IEEE Transactions on Electron Devices, 2022, 69, 3549-3556.	3.0	3
7	Impact of Reduced Gate-Source Spacing on Indium Phosphide High Electron Mobility Transistor Performance. Physica Status Solidi (A) Applications and Materials Science, 2021, 218, 2000191.	1.8	2
8	High-Speed Steep-Slope GaInAs Impact Ionization MOSFETs (I-MOS) With $SS = 1.25 \text{ mV/dec}$ Part I: Material and Device Characterization, DC Performance, and Simulation. IEEE Transactions on Electron Devices, 2022, 69, 3542-3548.	3.0	2
9	New GaInAs/InAs/InP Composite Channels for mm-Wave Low-Noise InP HEMTs. , 2019, , .		1
10	Evaluation of energy barriers for topological transitions of Si self-interstitial clusters by classical molecular dynamics and the kinetic activation-relaxation technique. , 2017, , .		0
11	Novel Vitrified-Bond Ultra-Fine Grinding Technology for SiC Polishing. Materials Science Forum, 0, 1062, 155-159.	0.3	0